

## SB1200 SCHOTTKY RECTIFIER

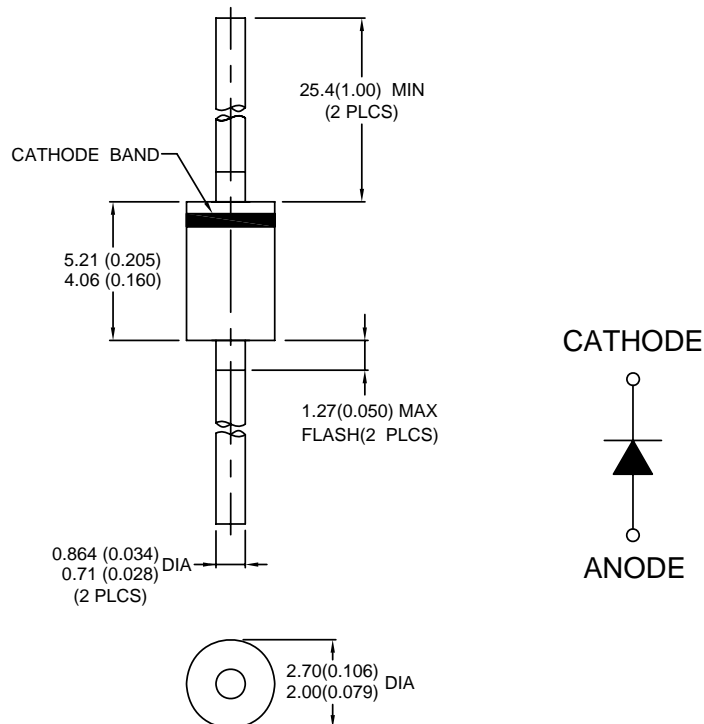
### Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Disk drives
- Battery charging

### Features:

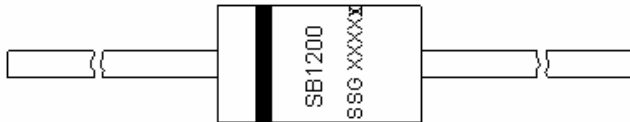
- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- Surge Overload Rating to 50A Peak
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability
- Classification Rating 94V-0
- Green Products in Compliance with the RoHS Directive
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Mechanical Dimensions: In mm



**DO-41**

**Marking Diagram:**



Where XXXXX is YYWWL

- SB = Device Type
- 1 = Forward Current (1A)
- 200 = Reverse Voltage (200V)
- SSG = SSG
- YY = Year
- WW = Week
- L = Lot Number

**Cautions :** Molding resin  
Epoxy resin UL:94V-0

**Ordering Information:**

Device	Package	Shipping
SB1200	DO-41 (Pb-Free)	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

**Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	200	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle @TC =105°C rectangular wave form	1.0	A
Max. Peak One Cycle Non-Repetitive Surge Current	$I_{FSM}$	8.3 ms, half Sine pulse	20	A



**Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	$V_{F1}$	@ 1A, Pulse, $T_J = 25^\circ\text{C}$	0.92	V
	$V_{F2}$	@ 1A, Pulse, $T_J = 125^\circ\text{C}$	0.76	V
Max. Reverse Current	$I_{R1}$	@ $V_R = \text{rated VR}$ $T_J = 25^\circ\text{C}$	0.5	mA
	$I_{R2}$	@ $V_R = \text{rated VR}$ $T_J = 100^\circ\text{C}$	1.0	mA
Typical Junction Capacitance	$C_j$	@ $V_R = 5.0\text{ V}$ , $T_c = 25^\circ\text{C}$ $f_{\text{SIG}} = 1\text{MHz}$	20	pF
Max. Voltage Rate of Change	dv/dt	-	10,000	v/us

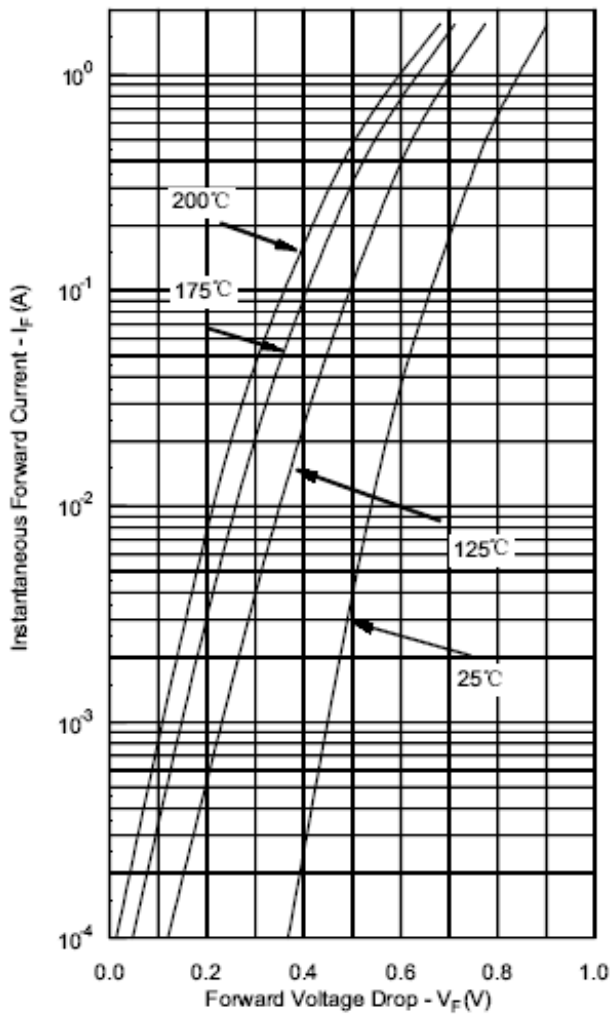
\* Pulse Width < 300μs, Duty Cycle <2%

**Thermal-Mechanical Specifications:**

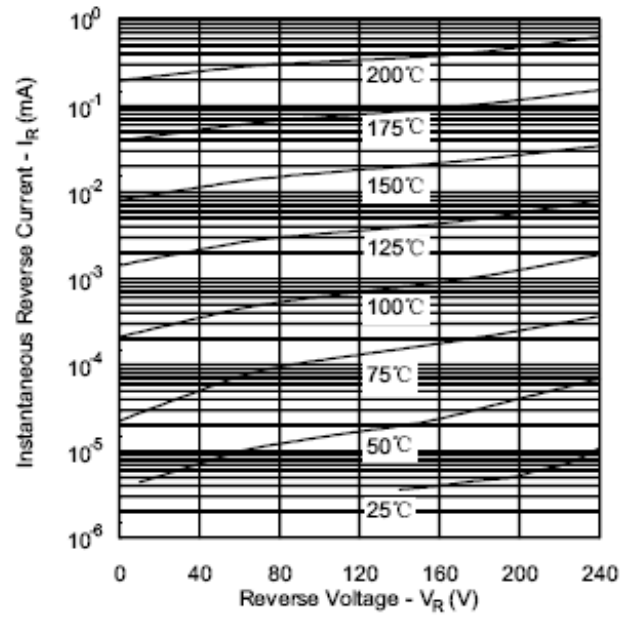
Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	$T_J$	-	-55 to +150	$^\circ\text{C}$
Max. Storage Temperature	$T_{\text{stg}}$	-	-55 to +150	$^\circ\text{C}$
Maximum Thermal Resistance, Junction to Ambient	$R_{\theta\text{JA}}$	DC operation	140	$^\circ\text{C/W}$
Approximate Weight	wt	-	0.35	g
Case Style	DO-41			



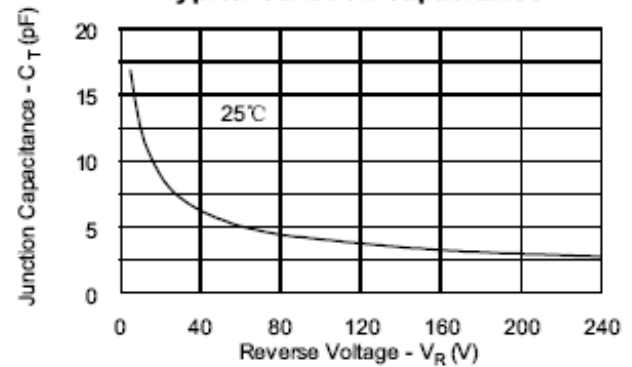
**Typical Forward Characteristics**



**Typical Reverse Characteristics**



**Typical Junction Capacitance**





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